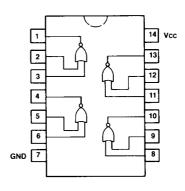
LS02

Quad 2-Input Positive NOR Gate

The LS02 is a bipolar, NPN, sealed-junction, silicon integrated circuit. It is manufactured in low-power Schottky technology and is available in a wire-bonded, 14-pin plastic DIP or surface mount package.



Electrical Characteristics

 $VCC = 5.0 \pm 0.5 \text{ V}, TA = -55 \text{ to } +125 ^{\circ}\text{C} \text{ (WA-LS)}$

 $VCC = 5.0 \pm 0.25 \text{ V}, TA = 0 \text{ to } 70^{\circ}\text{C (WP90222L2)}$

 $VCC = 5.0 \pm 0.5 \text{ V}$, TA = -40 to +85°C (WA-LSD, WP91397L2)

		WA-LS		WP, WA-LSD		
Parameter	Symbol	Min	Max	Min	Max	Units
Output Voltage, Vcc = 4.5 V (WA-LS), 4.75 V (WP, WA-LSD) Low, IoL = 4.0 mA IoL = 8.0 mA High, IoH = -0.4 mA	4U _{Võ} em Vol Voн	 2.5	0.4 0.5 —	_ _ 2.7	0.4 0.5 —	V V
Input Voltage, VCC = 4.5 V (WA-LS), 4.75 V (WP, WA-LSD) Low High Clamp, IIN = -18.0 mA	VIL VIH VIK	2.0 —	0.7 7.5 –1.5	2.0 —	0.8* 5.5 –1.5	V V
Input Current, Vcc = 5.5 V (WA-LS), 5.25 V (WP, WA-LSD) Low, VIL = 0.4 V High, VIH = 2.7 V @ VI max, VI = 7.0 V (WA-LS), 5.5 V (WP, WA-LSD)	IIL IIH It	_ _ _	-0.4 20.0 0.1	_ _ _	-0.4 20.0 0.1	mA μA mA
Output Current, VCC = 5.5 V (WA-LS), 5.25 V (WP, WA-LSD) Short-Circuit	los	-20.0	-100.0	-20.0	-100.0	mA
Supply Current, Vcc = 5.5 V (WA-LS), 5.25 V (WP, WA-LSD) Output Low Output High	ICCH		5.4 3.2	_	5.4 3.2	mA mA

^{*} WA-LSD, WP91397L2: Vil = 0.7 V

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Timing Characteristics

VCC = 5.0 V, TA = 25°C, CL = 15 pF

		WA-LS		WP, WA-LSD		
Parameter	Symbol	Min	Max	Min	Max	Units
Propagation Delay Low-to-High High-to-Low	tplh tphl	_	10.0 10.0	_	15.0 15.0	ns ns

Maximum Ratings

Power supply voltage (Vcc)	
Operating temperature (TA)	WA-LS: -55 to +125°C
	WP90222L2: 0 to 70°C
	WA-LSD, WP91397L2: -40 to +85°C
Storage temperature (Tstg)	65 to +150°C
Maximum ratings are defined as the limiting conditions that the use of circuit and environmental conditions. If any rating is exceeded,	er can apply to the device under all variations permanent damage to the device may result.
Bonding or soldering of the external leads of this device can be po	erformed safely at temperatures up to 300°C

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